General Description

The UM4601/UM4611/UM8601/UM8611 is a (L-C) low pass filter array with integrated TVS diodes. It is designed to suppress unwanted EMI signals and provide electrostatic discharge (ESD) protection in portable electronic equipment. This device utilizes solid-state silicon-avalanche technology for superior clamping performance and DC electrical characteristics. They have been optimized for protection of color LCD and camera lines in cellular phones and other portable electronics.

The device consists of identical circuits comprised of TVS diodes for ESD protection, and an inductor - capacitor network for EMI filtering. A typical inductor value of 17nH and a capacitor value of 15pF are used to achieve 24dB minimum attenuation from 800MHz to 2.7GHz. The TVS diodes provide effective suppression of ESD voltages in excess of ± 15 kV (air discharge) and ± 8 kV (contact discharge) per IEC 61000-4-2, level 4.

The UM4601 is in a RoHS compliant DFN8 2.0×2.0 package, the UM4611 is in a RoHS compliant DFN8 1.7×1.3 package, the UM8601 is in a RoHS compliant DFN16 4.0×1.6 package and the UM8611 is in a RoHS compliant DFN16 3.3×1.3 package. The leads are finished with lead-free. The small package makes it ideal for use in portable electronics such as cell phones, digital still cameras, and PDAs.

Applications

- Color LCD Protection
- Cell Phone CCD Camera Lines
- Clamshell Cell Phones

Features

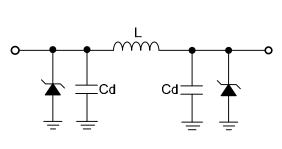
- Bidirectional EMI Filter with Integrated TVS for ESD Protection
- ESD Protection to IEC 61000-4-2 (ESD) Level 4, ±15kV (Air), ±8kV (Contact)
- Filter Performance: 24dB Minimum Attenuation from 800MHz to 2.7GHz
- TVS Working Voltage: 5V
- Inductor: 17nH (Typical)
- Capacitors: 15pF (Typical at $V_R=2.5V$)
- Protection and Filtering for Multi Lines
 - UM4601/4611: Four Lines UM8601/8611: Eight Lines
- Solid-State Technology

Ordering Information

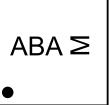
Part Number	Working Voltage	Packaging Type	Channel	Marking Code	Shipping Qty
UM4601	5.0V	DFN8 2.0×2.0	4	ABA	
UM4611	5.0V	DFN8 1.7×1.3	4	AN	3000pcs/7Inch
UM8601	5.0V	DFN16 4.0×1.6	8	8601	Tape & Reel
UM8611	5.0V	DFN16 3.3×1.3	8	8611	

Pin Configurations

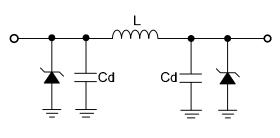
Top View



Device Schematic (4X)



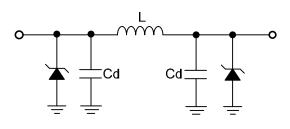
M: Month Code UM4601 DFN8 2.0×2.0



Device Schematic (4X)



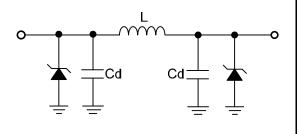
M: Month Code UM4611 DFN8 1.7×1.3



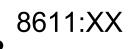
Device Schematic (8X)



XX: Week Code UM8601 DFN16 4.0×1.6



Device Schematic (8X)



XX: Week Code UM8611 DFN16 3.3×1.3

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	$ m V_{ESD}$	±20 ±15	kV
Junction Temperature	T_{J}	125	°C
Operating Temperature Range	T_{OP}	-40 to 85	°C
Storage Temperature Range	T_{STG}	-55 to 150	°C

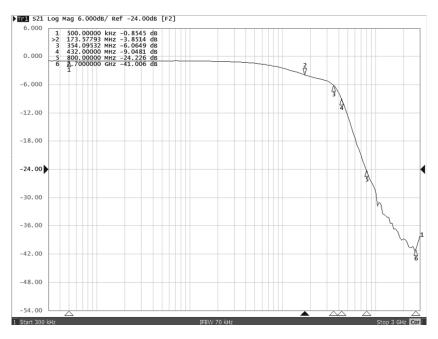
Electrical Characteristics

(T_J=25°C, unless otherwise noted)

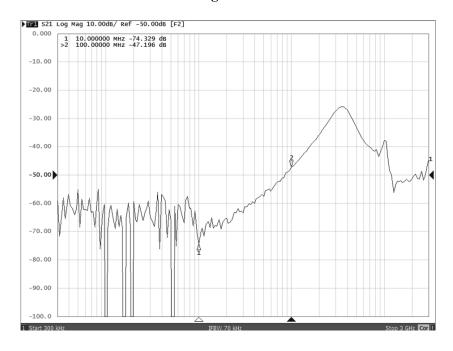
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
TVS Reverse Stand-Off Voltage	V_{RWM}				5	V
TVS Reverse Breakdown Voltage	$ m V_{BR}$	I _T =1mA	6	8	10	V
TVS Reverse Leakage Current	I_R	$V_{RWM}=3.3V$			0.1	μΑ
DC Resistance	R_{cc}			10		Ω
Roll-Off Frequency at -6dB Attenuation	f_R	$Z_{\text{source}} = Z_{\text{load}} = 50\Omega$		350		MHZ
Filter Cut-Off Frequency	fc	$Z_{\text{source}} = Z_{\text{load}} = 50\Omega$		150		MHZ
Inductance	L			17		nН
Capacitance	C_d	V_R =2.5V, f=1MHZ		15		pF
Total Capacitance	C_{total}	Input to GND, Each Line V _R =2.5V, f=1MHZ	24	30	36	pF

Typical Operating Characteristics

Typical Insertion Loss



Analog Crosstalk



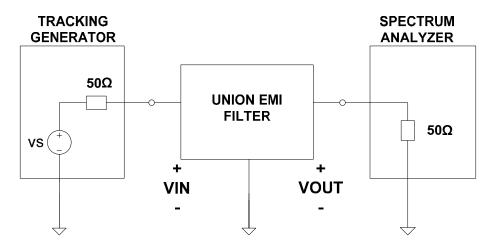
Applications Information

Insertion Loss

Insertion Loss (IL) is used to describe the transmission coefficient between two points in a circuit often described in terms of dB. When examining S parameters, S21 is often described as insertion loss. Insertion Loss and S21 will be used interchangeably from here on out. The insertion loss of a circuit with VOUT and VIN would be expressed as

 $IL \!\!=\!\! S_{21}(dB) \!\!=\!\! 20 log(V_{OUT}\!/V_{IN}\,)$

The setup for measuring insertion loss in a 50Ω system is shown in the figure below. It will be analyzed in a 50Ω environment, so the source impedance and load impedance is 50Ω . The transfer functions then can be analyzed in terms of insertion loss (S21).



Test Conditions: Source Impedance= 50Ω Load Impedance= 50Ω Input Power=0dBm

Cut Off Frequency

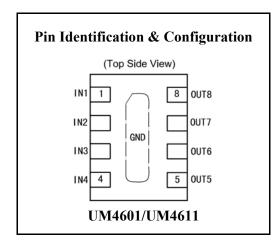
Cut off Frequency is the frequency at which the signal strength is 3.0dB less than it is Pass Band 3.0dB of attenuation equates to half the original signal power. The Pass Band is the range of frequencies that are allowed to "pass" through a filter with minimal attenuation. For our purposes it starts from DC and ends at the cut off frequency.

Device Connection

The UM4601/UM4611/UM8601/UM8611 is comprised of identical circuits consisting of a low pass filter for EMI suppression and dual TVS diodes for ESD protection. The device is in an 8-pin DFN and 16-pin DFN package. Electrical connection is made to all the pins located at the bottom of the device. A center tab serves as the ground connection. The device has a flow through design for easy layout. All path lengths should be kept as short as possible to minimize the effects of parasitic inductance in the board traces.

Ground Connection Recommendation

Parasitic inductance (L) present in the board layout will affect the filtering performance of the device. As frequency (f) increases, the effect of the inductance becomes more dominant. This effect is given by Equation 1.



Pin	Identification
1-4	Input Lines
5-8	Output Lines
Center Tab	Ground

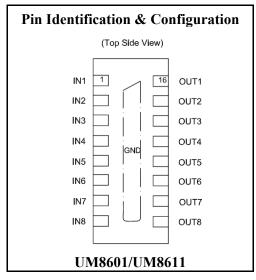
Equation 1: The Impedance of an Inductor at Frequency XLF

$$XLF(L,f) = 2 \times_{\pi} \times f \times L$$

Where:

L= Inductance (H)

f = Frequency (Hz)



Pin	Identification
1-8	Input Lines
9-16	Output Lines
Center Tab	Ground

Equation 1: The Impedance of an Inductor at Frequency XLF

$$XLF(L, f) = 2 \times \pi \times f \times L$$

Where:

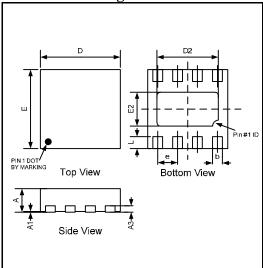
L= Parasitic Inductance in the PCB (H)

f = Frequency (Hz)

Package Information

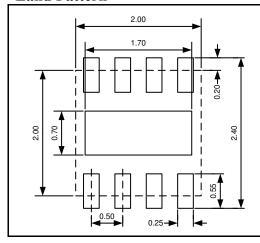
UM4601: DFN8 2.0×2.0

Outline Drawing



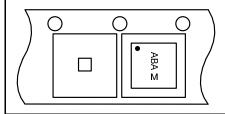
DIMENSIONS							
C	MILLIMETERS			INCHES			
Symbol	Min	Тур	Max	Min	Тур	Max	
A	0.55	-	0.80	0.022	-	0.031	
A1	0.00	-	0.05	0.000	-	0.002	
A3	0.20REF			0.008REF			
b	0.18	-	0.30	0.007	•	0.012	
D	1.924	2.00	2.076	0.076	0.079	0.082	
D2	1.35	-	1.80	0.053	-	0.071	
Е	1.924	2.00	2.076	0.076	0.079	0.082	
E2	0.75	-	1.00	0.030	-	0.039	
e	0.50TYP			0	0.020TY	P	
L	0.20	0.30	0.40	0.008	0.012	0.016	

Land Pattern



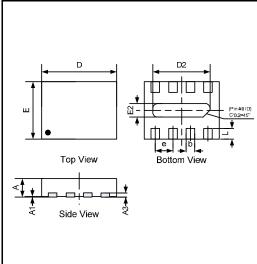
NOTES:

- 1. Compound dimension: 2.00×2.00;
- 2. Unit: mm;
- 3. General tolerance ± 0.05 mm unless otherwise specified;
- 4. The layout is just for reference.



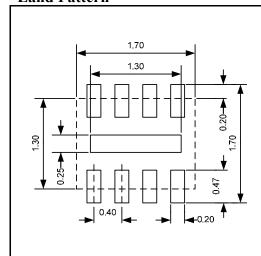
UM4611: DFN8 1.7×1.3

Outline Drawing



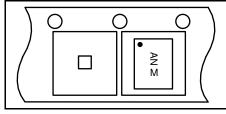
DIMENSIONS								
6 1 1	MIL	LIMET	ΓERS	INCHES				
Symbol	Min	Тур	Max	Min	Тур	Max		
A	0.45	0.55	0.60	0.018	0.022	0.024		
A1	0.00	-	0.05	0.000	-	0.002		
A3	0).15RE	F	0.006REF				
b	0.15	0.20	0.25	0.006	0.008	0.010		
D	1.624	1.70	1.776	0.064	0.067	0.070		
D2	0.85	-	1.40	0.033	ı	0.055		
Е	1.25	1.30	1.426	0.049	0.051	0.056		
E2	0.20	-	0.50	0.008	-	0.020		
e	0.40TYP			0	.016TY	P		
L	0.17	-	0.37	0.007	-	0.015		

Land Pattern



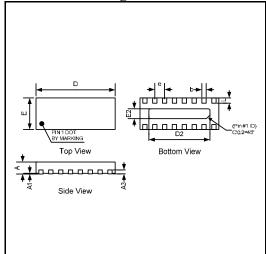
NOTES:

- 1. Compound dimension: 1.70×1.30;
- 2. Unit: mm;
- 3.General tolerance ± 0.05 mm unless otherwise specified;
- 4. The layout is just for reference.



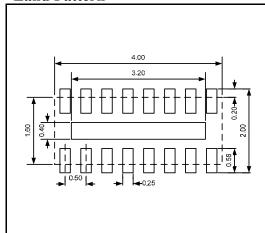
UM8601: DFN16 4.0×1.6

Outline Drawing



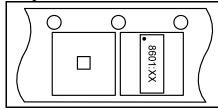
DIMENSIONS								
Cl1	MILLIMETERS			INCHES				
Symbol	Min	Тур	Max	Min	Тур	Max		
A	0.50	1	0.80	0.020	1	0.031		
A1	0.00	1	0.05	0.000	1	0.002		
A3	0.203REF			0.008REF				
b	0.15	-	0.30	0.006	-	0.012		
D	3.924	4.00	4.076	0.154	0.157	0.160		
D2	2.95	-	3.30	0.116	-	0.130		
Е	1.524	1.60	1.676	0.060	0.063	0.066		
E2	0.30	-	0.60	0.012		0.024		
e	0.50TYP			0	.020TY	P		
L	0.15	-	0.38	0.006	-	0.015		

Land Pattern



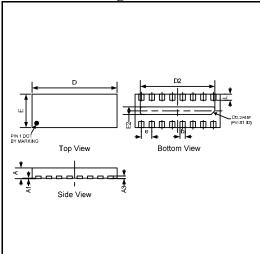
NOTES:

- 1. Compound dimension: 4.00×1.60;
- 2. Unit: mm;
- 3. General tolerance ± 0.05 mm unless otherwise specified;
- 4. The layout is just for reference.



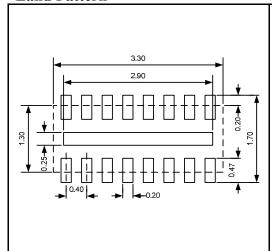
UM8611: DFN16 3.3×1.3

Outline Drawing



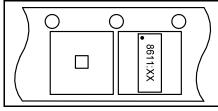
DIMENSIONS								
C11	MILLIMETERS			INCHES				
Symbol	Min	Тур	Max	Min	Тур	Max		
A	0.47	0.55	0.60	0.019	0.022	0.024		
A1	0.00	-	0.05	0.000	-	0.002		
A3	0.15REF			0.006REF				
b	0.15	0.20	0.25	0.006	0.008	0.010		
D	3.224	3.30	3.376	0.127	0.130	0.133		
D2	2.45	1	3.00	0.096	-	0.118		
Е	1.25	1.30	1.426	0.049	0.051	0.056		
E2	0.20	-	0.50	0.008	-	0.020		
e	0.40TYP			0	.016TY	P		
L	0.17	-	0.37	0.007	-	0.015		

Land Pattern



NOTES:

- 1. Compound dimension: 3.30×1.30;
- 2. Unit: mm;
- 3. General tolerance ± 0.05 mm unless otherwise specified;
- 4. The layout is just for reference.



GREEN COMPLIANCE

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